
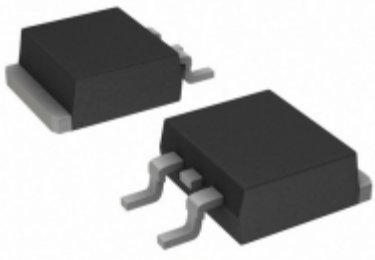



	<h2 style="color: red;">FQB3P20TM</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQB3P20TM</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 200V 2.8A D2PAK</p> <p><b>Datenblätter:</b>  <a href="#">FQB3P20TM.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 2245 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQB3P20TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 200V 2.8A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	2245 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 52W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.8A (Tc)
Rds On (Max) @ Id, Vgs	2.7 Ohm @ 1.4A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	250pF @ 25V
Verpackung	Tape & Reel (TR)



















































FQB3P20TM ist neu im Original, Suche FQB3P20TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB3P20TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB3P20TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB3N90TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 3.6A D2PAK</p>	 <p><b>FQB3P20TM</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 2.8A D2PAK</p>	 <p><b>FQB3N90TM</b> Fairchild/ON Semiconductor MOSFET N-CH 900V 3.6A D2PAK</p>	 <p><b>FQB41N15D</b> FAIRCHILD FAIRCHILD TO-263</p>
 <p><b>FQB3P20</b> FSC FQB3P20 FSC</p>	 <p><b>FQB3P50TM</b> Fairchild/ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK</p>	 <p><b>FQB3N90</b> FCS FQB3N90 FCS</p>	 <p><b>FQB3P50TM</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK</p>

### heiße Teile

Mehr

 FQB33N10LTM	 FQB33N10TM	 FQB33N10TM	 FQB34N20	 FQB34N20L
 FQB34N20LTM	 FQB34N20LTM	 FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10
 FQB34P10TM	 FQB34P10TM	 FQB34P10TM_F085	 FQB3N25TM	 FQB3N25TM
 FQB3N30TM	 FQB3N30TM	 FQB3N40TM	 FQB3N40TM	 FQB3N60C
 FQB3N80TM	 FQB3N80TM	 FQB3N90TM	 FQB3N90TM	 FQB3P20TM
 FQB3P50TM	 FQB3P50TM	 FQB44N10	 FQB44N10TM	 FQB44N10TM
 FQB46N15	 FQB46N15TM	 FQB47P06	 FQB47P06TM	 FQB4N20L
 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM	 FQB4N20TM	 FQB4N25TM
 FQB4N25TM	 FQB4N20TM	 FQB4N50TM	 FQB4N50TM	 FQB4N60C
 FQB4N80TM	 FQB4N80TM	 FQB4N90TM	 FQB4N90TM	 FQB4P25TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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